

PBSS305NX,115 Datasheet

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DiGi Electronics Part Number
Manufacturer
Manufacturer Product Number
Description
Detailed Description

PBSS305NX,115-DG

Nexperia USA Inc.

PBSS305NX,115

TRANS NPN 80V 4.6A SOT89

Bipolar (BJT) Transistor NPN 80 V 4.6 A 110MHz 2.1 W Surface Mount SOT-89

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PBSS305NX,115	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	4.6 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, Ic:
80 V	240mV @ 230mA, 4.6A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	180 @ 2A, 2V
Power - Max:	Frequency - Transition:
2.1 W	110MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
TO-243AA	SOT-89
Base Product Number:	
PBSS305	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	



80 V, 4.6 A NPN low VCEsat transistor

14 February 2024

Product data sheet

1. General description

NPN low V_{CEsat} transistor in a SOT89 (SC-62/TO-243) small and flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS305PX

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- + High collector current capability ${\rm I}_{\rm C}$ and ${\rm I}_{\rm CM}$
- + High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors
- AEC-Q101 qualified

3. Applications

- High-voltage DC-to-DC conversion
- High-voltage MOSFET gate driving
- High-voltage motor control
- High-voltage power switches (e.g. motors, fans)
- Automotive applications

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	80	V
I _C	collector current		-	-	4.6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	9.2	А
R _{CEsat}	collector-emitter saturation resistance	I _C = 4 A; I _B = 200 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	38	53	mΩ

nexperia

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		
3	В	base		B — [
			3 2 1	E
			SOT89	sym123

6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
PBSS305NX	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<u>SOT89</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS305NX	%5F

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

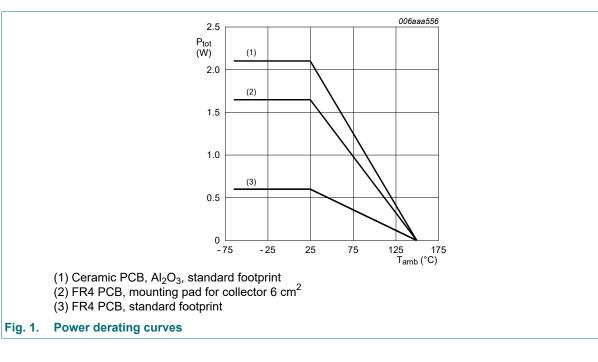
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	80	V
V _{CEO}	collector-emitter voltage	open base		-	80	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
l _C	collector current			-	4.6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	9.2	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1.65	W
			[3]	-	2.1	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



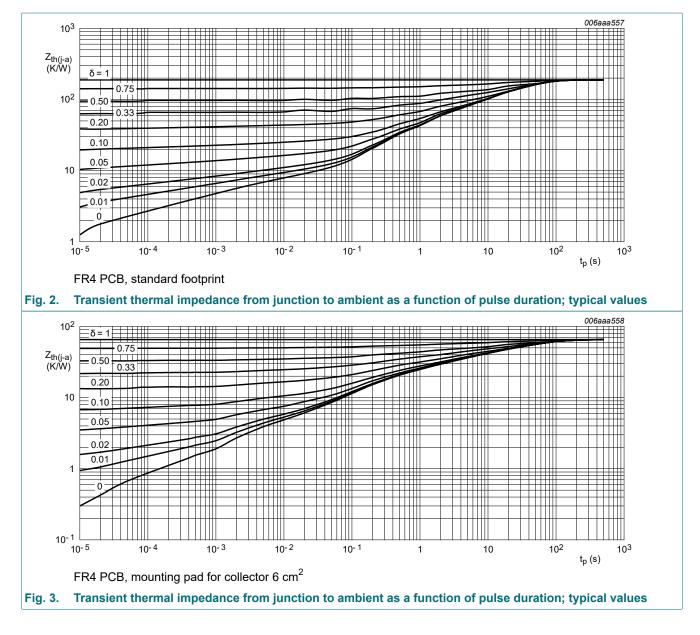
9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	in free air	[1]	-	-	208	K/W	
			[2]	-	-	76	K/W
		[3]	-	-	60	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

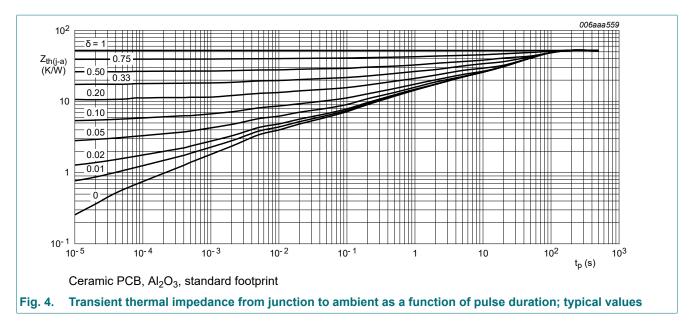
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



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80 V, 4.6 A NPN low VCEsat transistor



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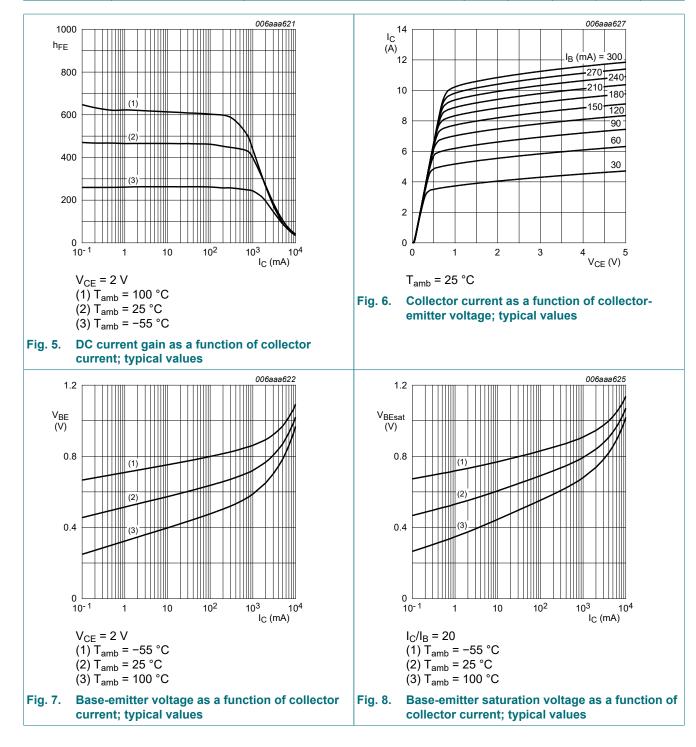
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
сво	collector-base cut-off	V _{CB} = 80 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA	
	current	V _{CB} = 80 V; I _E = 0 A; T _i = 150 °C	-	-	50	μA	
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C}$	-	-	100	nA	
h _{FE}	DC current gain	V_{CE} = 2 V; I _C = 0.5 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	300	470	-		
			$ \begin{array}{l} V_{CE} \texttt{= 2 V; } I_{C} \texttt{= 1 A; pulsed; } t_{p} \texttt{\leq 300 } \mu s; \\ \delta \texttt{\leq } 0.02; T_{amb} \texttt{= 25 }^\circ C \end{array} $	250	420	-	
		$ \begin{array}{l} V_{CE} = 2 \; V; \; I_{C} = 2 \; A; \; pulsed; \; t_{p} \leq \; 300 \; \mu s; \\ \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ}C \end{array} $	180	280	-		
		$ \begin{array}{l} V_{CE} \texttt{= 2 V; } I_{C} \texttt{= 4 A; pulsed; } t_{p} \texttt{\leq 300 } \mu s; \\ \delta \texttt{\leq } 0.02; T_{amb} \texttt{= 25 °C} \end{array} $	90	140	-		
		$ \begin{array}{l} V_{CE} = 2 \; V; \; I_{C} = 5 \; A; \; pulsed; \; t_{p} \leq \; 300 \; \mu s; \\ \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ}C \end{array} $	70	110	-		
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 0.5 A; I_{B} = 50 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	25	40	mV	
		I_{C} = 1 A; I_{B} = 50 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	50	70	mV	
		I_{C} = 1 A; I_{B} = 10 mA; pulsed; $t_{p} \le$ 300 µs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	85	120	mV	
		I_C = 2 A; I_B = 40 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	105	140	mV	
		$ I_C = 4 \text{ A}; I_B = 200 \text{ mA}; \text{ pulsed}; t_p \leq \\ 300 \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 ^\circ\text{C} $	-	150	210	mV	
		I_{C} = 4 A; I_{B} = 400 mA; pulsed; $t_{p} \le$ 300 µs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	140	200	mV	
		$I_{C} = 4 \text{ A}; I_{B} = 80 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \mu\text{s}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$	-	210	320	mV	
		I_C = 4.6 A; I_B = 230 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	170	240	mV	
R _{CEsat}	collector-emitter saturation resistance	$\label{eq:lc} \begin{array}{l} I_{C} = 4 \; A; \; I_{B} = 200 \; mA; \; pulsed; \; t_{p} \leq \\ 300 \; \mus; \; \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ}C \end{array}$	-	38	53	mΩ	
		$ I_C = 4 \text{ A}; I_B = 80 \text{ mA}; \text{ pulsed}; t_p \leq 300 \ \mu\text{s}; \delta \leq 0.02; T_{amb} = 25 \ ^\circ\text{C} $	-	53	80	mΩ	
V _{BEsat}	base-emitter saturation voltage	I_C = 1 A; I_B = 100 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	0.82	0.9	V	
		$\label{eq:lc} \begin{array}{l} I_{C} = 4 \; A; \; I_{B} = 400 \; mA; \; pulsed; \; t_{p} \leq \\ 300 \; \mus; \; \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ}C \end{array}$	-	0.94	1.05	V	
V _{BEon}	base-emitter turn-on voltage	$ \begin{array}{l} V_{CE} = 2 \; V; \; I_{C} = 2 \; A; \; pulsed; \; t_{p} \leq \; 300 \; \mu s; \\ \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ}C \end{array} $	-	0.77	0.85	V	
t _d	delay time	$V_{CC} = 12.5 \text{ V}; \text{ I}_{C} = 3 \text{ A}; \text{ I}_{Bon} = 0.15 \text{ A};$	-	15	-	ns	
t _r	rise time	I _{Boff} = -0.15 A; T _{amb} = 25 °C	-	200	-	ns	
t _{on}	turn-on time		-	215	-	ns	
t _s	storage time	ļ	-	310	-	ns	
t _f	fall time] [-	245	-	ns	
t _{off}	turn-off time		-	555	-	ns	

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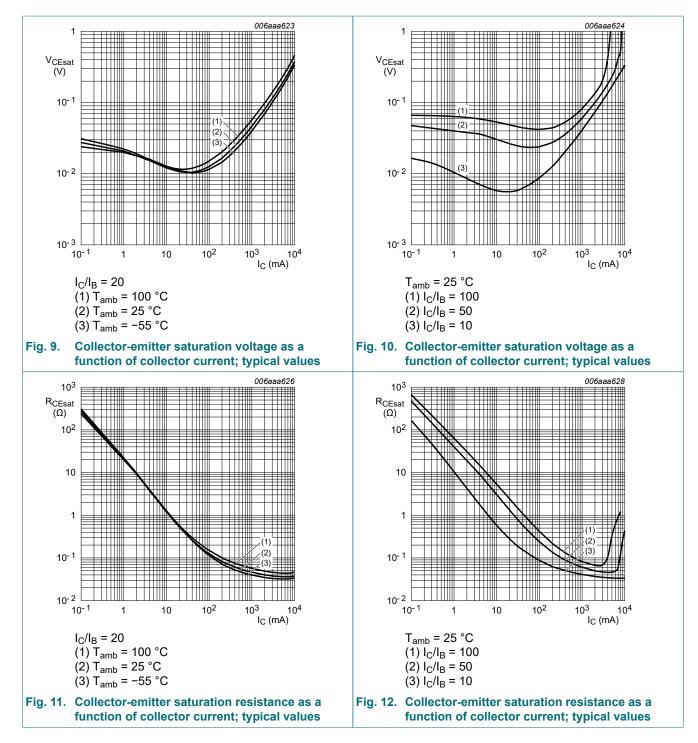
80 V, 4.6 A NPN low VCEsat transistor

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _T	transition frequency	V_{CE} = 10 V; I _C = 100 mA; f = 100 MHz; T _{amb} = 25 °C	-	110	-	MHz
C _c	collector capacitance	V_{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	30	50	pF



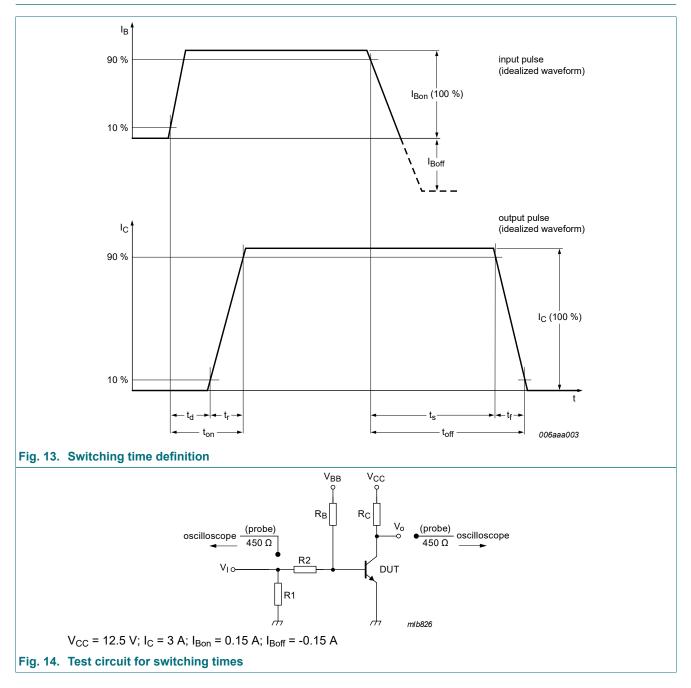
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80 V, 4.6 A NPN low VCEsat transistor



80 V, 4.6 A NPN low VCEsat transistor

11. Test information

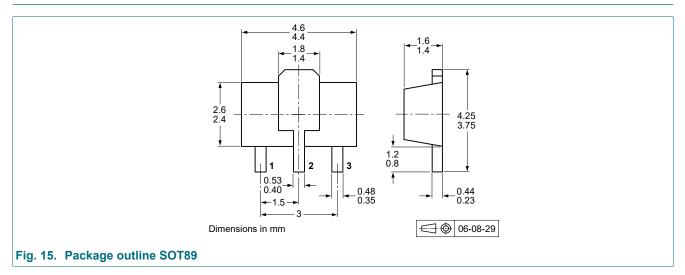


Quality information

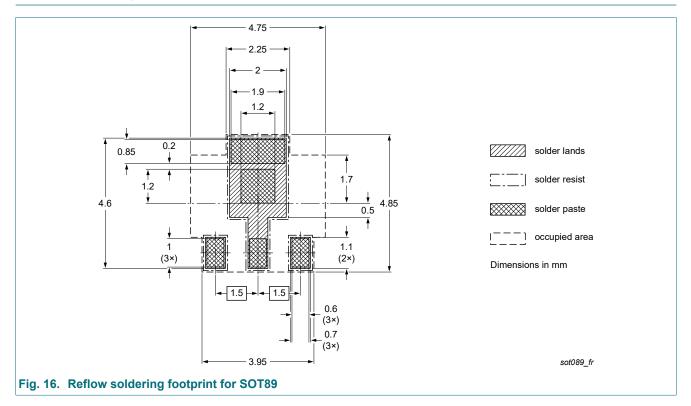
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

80 V, 4.6 A NPN low VCEsat transistor

12. Package outline



13. Soldering

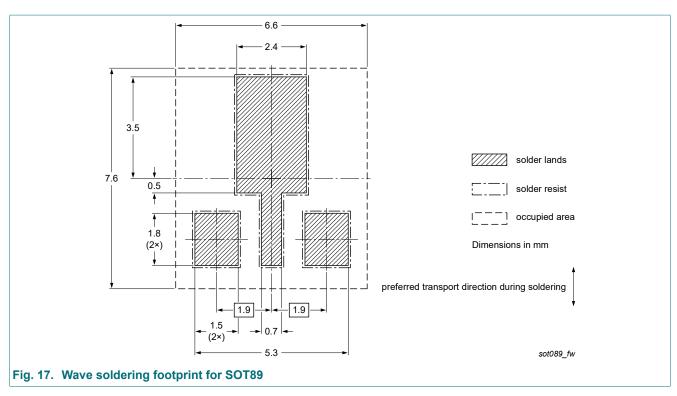


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14. Revision history

Table 8. Revision hi	story			
Data sheet ID	Release date	ate Data sheet status Change no		Supersedes
PBSS305NX v.3	20240214	Product data sheet	-	PBSS305NX_2
Modifications:	Nexperia. Legal texts ha 	this data sheet has been rede we been adapted to the new o ing information" removed.	•	
PBSS305NX_2	20091208	Product data sheet	-	PBSS305NX_1
PBSS305NX_1	20060817	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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